

0201N (.020 x .010)

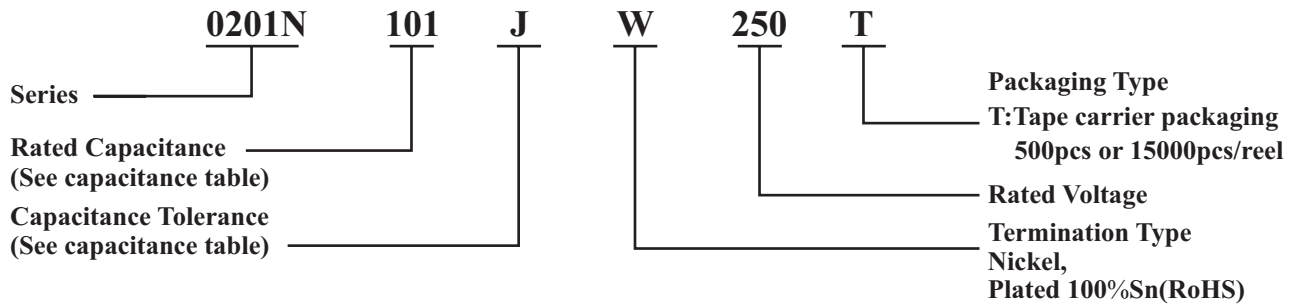
◆0201N Capacitance & Rated Voltage Table



Cap.pF	Code	Tol.	Rated WVDC	Cap.pF	Code	Tol.	Rated WVDC	Cap.pF	Code	Tol.	Rated WVDC
0.1	0R1	A,B, C,D	25V Code 250	2.2	2R2	A,B, C,D	25V Code 250	16	160	F,G, J,K	25V Code 250
0.2	0R2			2.4	2R4			18	180		
0.3	0R3			2.7	2R7			20	200		
0.4	0R4			3.0	3R0			22	220		
0.5	0R5			3.3	3R3			24	240		
0.6	0R6			3.6	3R6			27	270		
0.7	0R7			3.9	3R9			30	300		
0.8	0R8			4.3	4R3			33	330		
0.9	0R9			4.7	4R7			36	360		
1.0	1R0			5.1	5R1			39	390		
1.1	1R1			5.6	5R6	43		430			
1.2	1R2			6.2	6R2	47		470			
1.3	1R3			6.8	6R8	51		510			
1.4	1R4			7.5	7R5	56		560			
1.5	1R5			8.2	8R2	62		620			
1.6	1R6			9.1	9R1	68		680			
1.7	1R7			10	100	75		750			
1.8	1R8			11	110	82		820			
1.9	1R9			12	120	91		910			
2.0	2R0			13	130	100		101			
2.1	2R1			15	150						

Remark: special capacitance, tolerance and WVDC are available, consult with PASSIVE PLUS.


◆ Part Numbering



Code	A	B	C	D	F	G	J	K
Tolerance	± 0.05pF	± 0.1pF	± 0.25pF	± 0.5pF	± 1%	± 2%	± 5%	± 10%

◆ 0201N Chip Dimensions

unit: inch(millimeter)

Series	Term. Code	Type / Outlines	Capacitor Dimensions			Plated Material
			Length (L _c)	Width (W _c)	Thickness (T _c)	
0201N	W	 Chip	.024 ± .001 (0.60 ± 0.3)	.012 ± .001 (0.30 ± 0.03)	.012 ± .001 (0.30 ± 0.3)	Sn/Ni (RoHS)

Remark: for Non-Magnetic NP0 products please refer to page 81.

◆ Performance

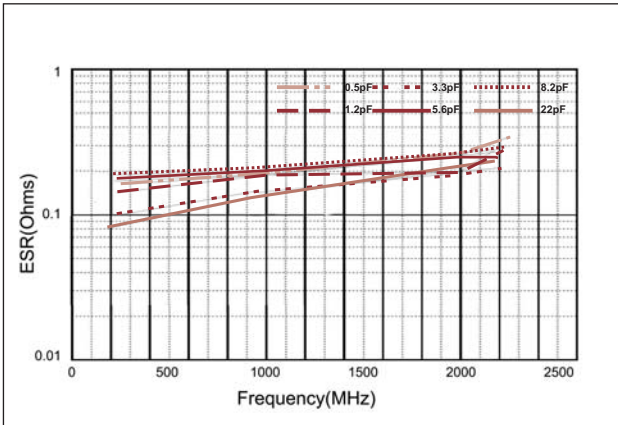
Item	Specifications
Quality Factor (Q)	2,000 min.
Insulation Resistance (IR)	10 ⁵ Megohms min. @ +25°C at rated WVDC. 10 ⁴ Megohms min. @ +125°C at rated WVDC.
Rated Voltage	25V
Dielectric Withstanding Voltage (DWV)	250% of rated voltage for 5 seconds.
Operating Temperature Range	-55°C to +125°C
Temperature Coefficient (TC)	0 ± 30ppm/°C
Capacitance Drift	± 0.02% or ± 0.02pF, whichever is greater.
Piezoelectric Effects	None

◆ Environmental Tests

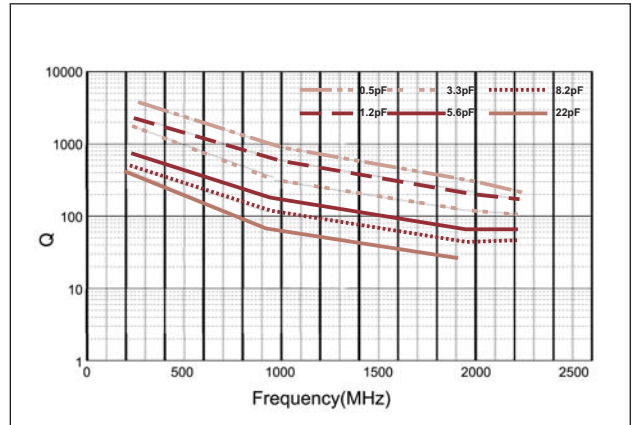
Item	Specifications	Method
Terminal Adhesion	Termination should not pull off. Ceramic should remain undamaged.	Linear pull force exerted on axial leads soldered to each terminal. 2.0lbs.
Resistance to soldering heat	No mechanical damage Capacitance change: - 1.0% ~ +2.0% Q>500 I.R. >10 G Ohms Breakdown voltage: 2.5 x WVDC	Preheat device to 150°C-180°C for 60 sec. Dip in 260±5°C solder for 10±1 sec. Measure after 24±2 hour cooling period.
Thermal Shock	No mechanical damage Capacitance change:±0.5% or 0.5pF max Q>2000 I.R. >10 G Ohms Breakdown voltage: 2.5 x WVDC	MIL-STD-202, Method 107, Condition A. At the maximum rated temperature (-55°C and 125°C) stay 30 minutes. The time of removing shall not be more than 3 minutes. Perform the five cycles.
Humidity, Steady State	No mechanical damage Capacitance change: ±0.5% or 0.5pF max. Q>300 I.R. >1 G Ohms Breakdown voltage: 2.5 x WVDC	MIL-STD-202, Method 106.
Low Voltage Humidity	No mechanical damage Capacitance change: ±0.3% or 0.3pF max. Q>300 I.R. >1 G Ohms Breakdown voltage: 2.5 x WVDC	MIL-STD-202, Method 103, Condition A, with 1.5 Volts D.C. applied while subjected to an environment of 85°C with 85% relative humidity for 240 hours minimum.
Life	No mechanical damage Capacitance change: ±2.0% or 0.5pF max. Q>500 I.R. >1 G Ohms Breakdown voltage: 2.5 x WVDC	MIL-STD-202, Method 108, for 1000 hours, at 125°C. 200% Rated voltage D.C. applied.

◆ **0201N Performance Curve**

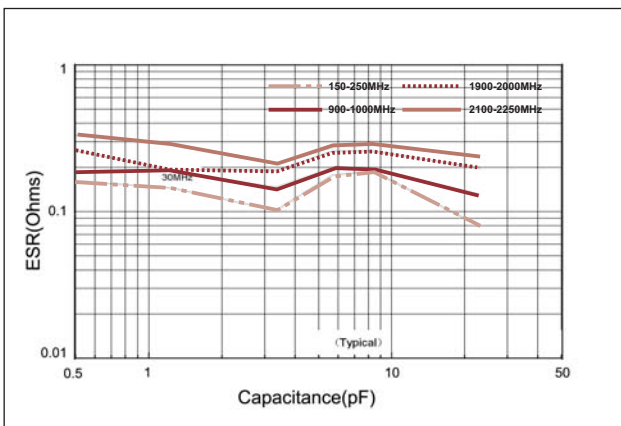
ESR vs Frequency



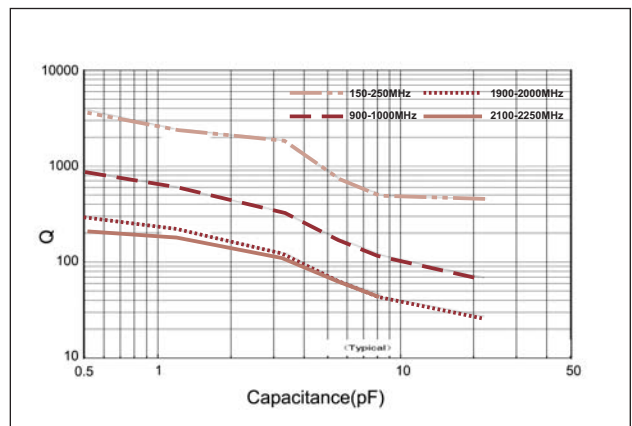
Q vs Frequency



ESR vs Capacitance



Q vs Capacitance



Series Resonant Frequency vs Capacitance

